

## Description

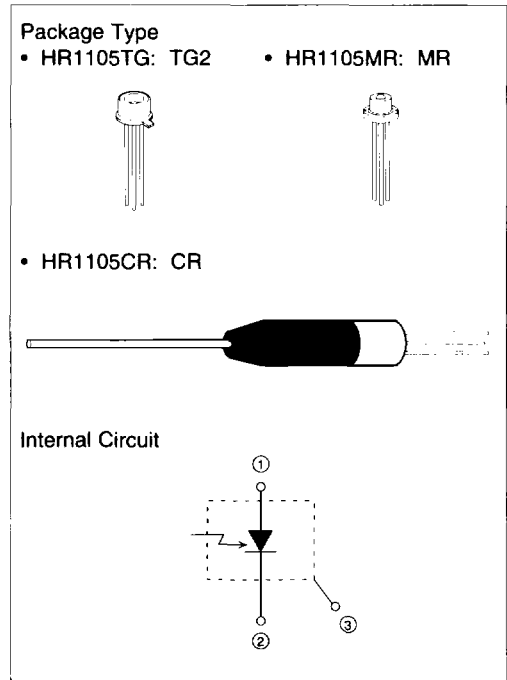
The HR1105TG/MR/CR are InGaAs PIN photodiodes which respond to a 1.0  $\mu\text{m}$  to 1.65  $\mu\text{m}$  band. Their fast pulse response makes them suitable as optical detectors for high-bit-rate optical fiber communication systems.

## Features

- Fast pulse response:  $t_r, t_f = 0.3 \text{ ns Typ.}$
- High sensitivity:  
 $S = 0.9 \text{ mA/mW Typ. } (\lambda_p = 1550 \text{ nm, TG/MR})$   
 $S = 0.8 \text{ mA/mW Typ. } (\lambda_p = 1550 \text{ nm, CR})$
- Low dark current:  $I_{\text{DARK}} = 1 \text{ nA Typ.}$
- Low capacitance:  
 $C_t = 0.8 \text{ pF Typ. (TG/MR)}$   
 $C_t = 0.9 \text{ pF Typ. (CR)}$
- Photodetectable area: 80  $\mu\text{m Dia.}$

## Fiber Specifications (HR1105CR)

Numerical aperture: 0.2  
 Core diameter: 50  $\mu\text{m}$   
 Outer diameter: 125  $\mu\text{m}$   
 Jacket diameter: 900  $\mu\text{m}$   
 Refractive index profile: GI  
 Fiber length: More than 500 mm



## Absolute Maximum Ratings ( $T_C = 25 \pm 3^\circ\text{C}$ )

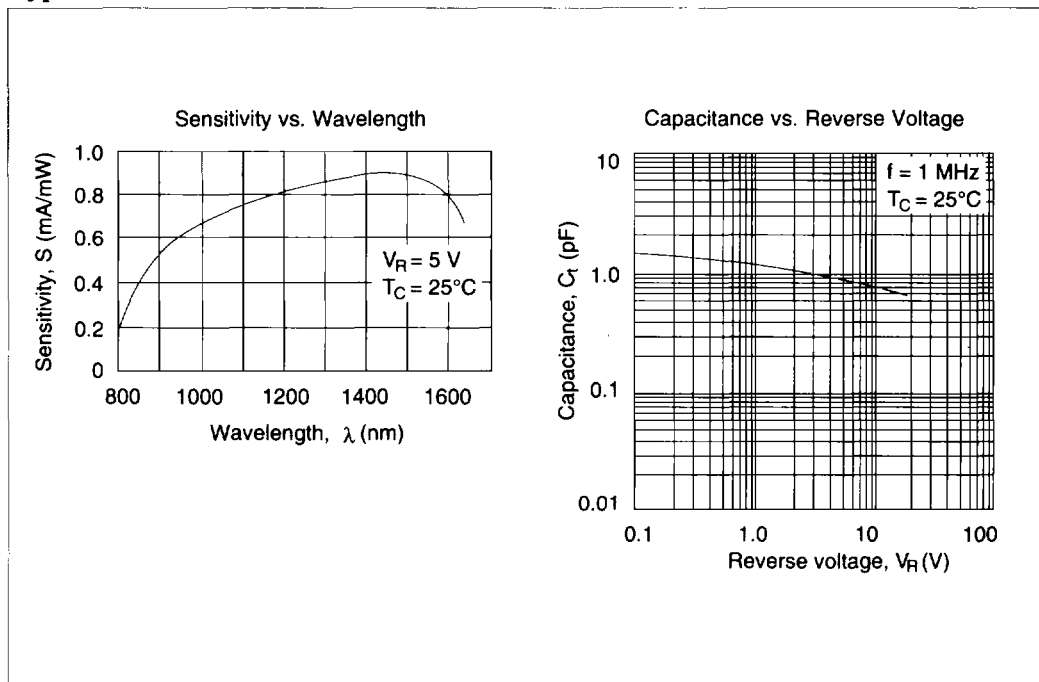
Item	Symbol	Rated Value	Unit
Reverse voltage	$V_R$	20	V
Forward current	$I_F$	5.0	mA
Reverse current	$I_R$	500	$\mu\text{A}$
Operating temperature	TG/MR $T_{\text{opr}}$	-40 to +80	$^\circ\text{C}$
	CR	-20 to +75	
Storage temperature	TG/MR $T_{\text{stg}}$	-45 to +100	$^\circ\text{C}$
	CR	-45 to +80	

# HR1105TG/MR/CR

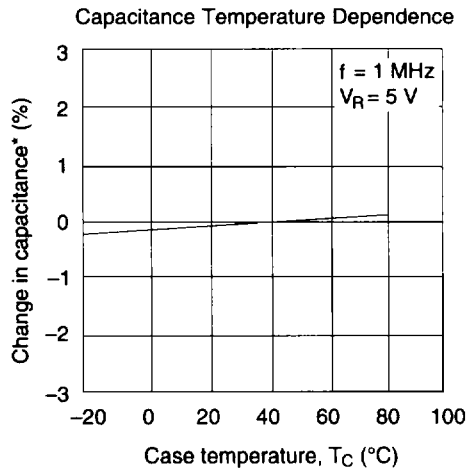
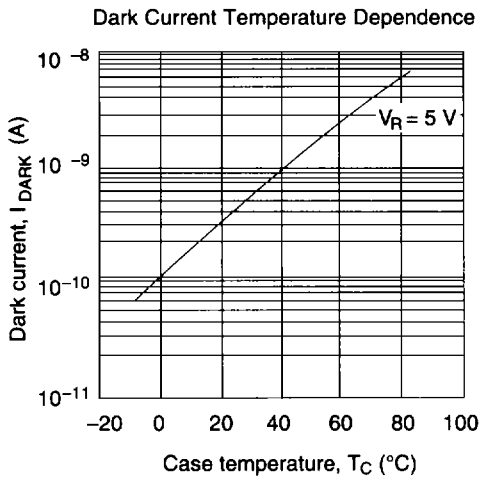
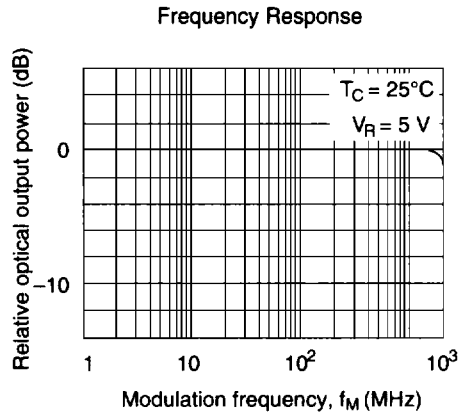
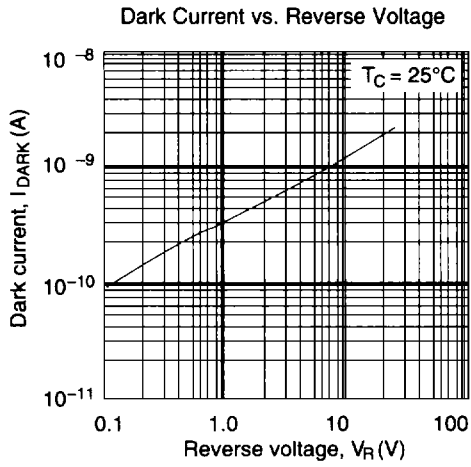
## Optical and Electrical Characteristics ( $T_C = 25^\circ\text{C}$ )

Item	Symbol	Min	Typ	Max	Units	Test Conditions
Dark current	HR1105TG/MR	$I_{\text{DARK}}$	—	1	10	nA $V_R = 5\text{ V}$
	HR1105CX	—	1	5		
Capacitance	HR1105TG/MR	$C_1$	—	0.8	1.2	pF $V_R = 5\text{ V}, f = 1\text{ MHz}$
	HR1105CR	—	0.9	1.3		
Sensitivity	HR1105TG/MR	$S_1$	0.73	0.85	—	mA/mW $V_R = 5\text{ V}, \lambda_p = 1300\text{ nm}$
	HR1105CR	—	0.63	0.78	—	
	HR1105TG/MR	$S_2$	—	0.9	—	mA/mW $V_R = 5\text{ V}, \lambda_p = 1550\text{ nm}$
	HR1105CR	—	—	0.8	—	
Sensitivity saturation bias voltage	$V_{R(S)}$	—	—	2	V	—
Rise time	$t_r$	—	0.3	—	ns	$V_R = 5\text{ V}, \lambda_p = 1300\text{ nm}$ $R_L = 50\ \Omega$
Fall time	$t_f$	—	0.3	—	ns	$V_R = 5\text{ V}, \lambda_p = 1300\text{ nm}$ $R_L = 50\ \Omega$

## Typical Characteristic Curves



Typical Characteristic Curves (cont.)



(\* Across terminal pins, relative to  $T_C = 25^\circ\text{C}$ )

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Part

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Typical Characteristic Curves (cont.)

